

ARPES study of NdNiO₃ heterostructures across the metal-insulator transition

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Abstract

The metal-insulator transitions (MITs) in complex oxides are often precursors to exotic ground states such as high-T_C superconductivity, CMR, and different types of charge-, spin- and orbital-ordered states¹. In this context, rare-earth nickelates (RNiO₃, where R = rare-earth elements) can be viewed as model systems, which exhibit temperature-driven MIT and magnetic/charge ordering and these can be tuned by changing R and hydrostatic pressure². In recent years, the novel routes to engineering thin films and heterostructures of RNiO₃ further offer the possibility to control the MIT with thickness via strain³. In this talk, I will present our recent results, obtained using in-situ PLD+ARPES system, and discuss the mechanism of the MIT in NdNiO₃ thin films grown on different substrates as well as magnetic under-layers^{4,5}. We observe three dimensional hole and electron Fermi surface (FS) pockets formed from strongly renormalized bands with well-defined quasiparticles. Upon cooling across the MIT, the quasiparticles lose coherence via a spectral weight transfer in NNO/NGO sample⁴. However, in NNO/LAO, the bands are apparently shifted upwards with an additional holelike pocket forming at the corner of the BZ. We observed significant difference in the electronic properties of NNO ultra-thin films when grown in the proximity with localized FM and itinerant AFM under-layers⁵. Our study suggests that substrate-induced strain and magnetism tunes the crystal field splitting, which changes the band structure and control the MIT via the formation of an electronic order^{4,5}.

1. M. Imada, A. Fujimori, and Y. Tokura, *Rev. Mod. Phys.*, 70, 1039 (1998).
2. M. Medarde, *J. Phys.: Condens. Matter*, 9, 1679 (1997) and reference therein.
3. R. Scherwitzl, et al., *Advanced Materials*, 22, 5517 (2010).
4. R. S. Dhaka, et al., *Phys. Rev. B*, 92, 035127 (2015).
5. Z. Ristic *, R. S. Dhaka *, et al., *Phys. Rev.*, (2016) to be submitted.